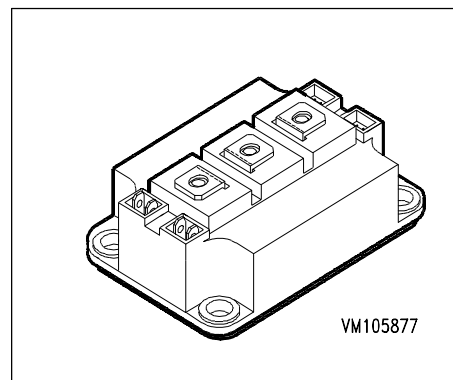


## IGBT Power Module

- Single switch with chopper diode at collector
- Chopper diode like diode of BSM300GA120DN2
- Package with insulated metal base plate



Type	$V_{CE}$	$I_C$	Package	Ordering Code
BSM 200 GAL 120 DN2	1200V	290A	HB 200GAL	C67070-A2301-A70

## Maximum Ratings

Parameter	Symbol	Values	Unit
Collector-emitter voltage	$V_{CE}$	1200	V
Collector-gate voltage	$V_{CGR}$	1200	
$R_{GE} = 20 \text{ k}\Omega$			
Gate-emitter voltage	$V_{GE}$	$\pm 20$	
DC collector current	$I_C$	290	A
$T_C = 25 \text{ }^\circ\text{C}$			
$T_C = 80 \text{ }^\circ\text{C}$		200	
Pulsed collector current, $t_p = 1 \text{ ms}$	$I_{Cpuls}$	580	
$T_C = 25 \text{ }^\circ\text{C}$			
$T_C = 80 \text{ }^\circ\text{C}$		400	
Power dissipation per IGBT	$P_{tot}$	1400	W
$T_C = 25 \text{ }^\circ\text{C}$			
Chip temperature	$T_j$	+ 150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-40 ... + 125	
Thermal resistance, chip case	$R_{thJC}$	$\leq 0.09$	K/W
Diode thermal resistance, chip case	$R_{thJCD}$	-	
Diode thermal resistance, chip-case, chopper	$R_{thJCDC}$	$\leq 0.125$	
Insulation test voltage, $t = 1 \text{ min.}$	$V_{is}$	2500	Vac
Creepage distance	-	20	mm
Clearance	-	11	
DIN humidity category, DIN 40 040	-	F	sec
IEC climatic category, DIN IEC 68-1	-	40 / 125 / 56	

**Electrical Characteristics**, at  $T_j = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

**Static Characteristics**

Gate threshold voltage $V_{GE} = V_{CE}, I_C = 8\text{ mA}$	$V_{GE(th)}$	4.5	5.5	6.5	V
Collector-emitter saturation voltage $V_{GE} = 15\text{ V}, I_C = 200\text{ A}, T_j = 25\text{ °C}$ $V_{GE} = 15\text{ V}, I_C = 200\text{ A}, T_j = 125\text{ °C}$	$V_{CE(sat)}$	- -	2.5 3.1	3 3.7	
Zero gate voltage collector current $V_{CE} = 1200\text{ V}, V_{GE} = 0\text{ V}, T_j = 25\text{ °C}$ $V_{CE} = 1200\text{ V}, V_{GE} = 0\text{ V}, T_j = 125\text{ °C}$	$I_{CES}$	- -	3 12	4 -	mA
Gate-emitter leakage current $V_{GE} = 20\text{ V}, V_{CE} = 0\text{ V}$	$I_{GES}$	-	-	400	nA

**AC Characteristics**

Transconductance $V_{CE} = 20\text{ V}, I_C = 200\text{ A}$	$g_{fs}$	108	-	-	S
Input capacitance $V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$	$C_{iss}$	-	13	-	nF
Output capacitance $V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$	$C_{oss}$	-	2	-	
Reverse transfer capacitance $V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$	$C_{rss}$	-	1	-	

**Electrical Characteristics**, at  $T_j = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

**Switching Characteristics, Inductive Load at  $T_j = 125\text{ °C}$** 

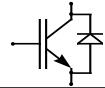
Turn-on delay time $V_{CC} = 600\text{ V}$ , $V_{GE} = 15\text{ V}$ , $I_C = 200\text{ A}$ $R_{Gon} = 4.7\ \Omega$	$t_{d(on)}$	-	110	220	ns
Rise time $V_{CC} = 600\text{ V}$ , $V_{GE} = 15\text{ V}$ , $I_C = 200\text{ A}$ $R_{Gon} = 4.7\ \Omega$	$t_r$	-	80	160	
Turn-off delay time $V_{CC} = 600\text{ V}$ , $V_{GE} = -15\text{ V}$ , $I_C = 200\text{ A}$ $R_{Goff} = 4.7\ \Omega$	$t_{d(off)}$	-	550	800	
Fall time $V_{CC} = 600\text{ V}$ , $V_{GE} = -15\text{ V}$ , $I_C = 200\text{ A}$ $R_{Goff} = 4.7\ \Omega$	$t_f$	-	80	120	

**Free-Wheel Diode**

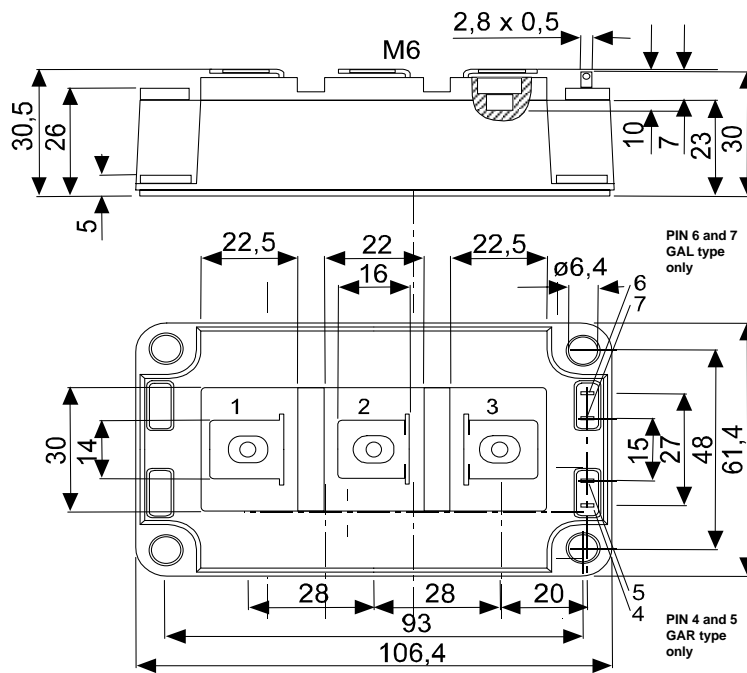
Diode forward voltage $I_F = 200\text{ A}$ , $V_{GE} = 0\text{ V}$ , $T_j = 25\text{ °C}$ $I_F = 200\text{ A}$ , $V_{GE} = 0\text{ V}$ , $T_j = 125\text{ °C}$	$V_F$	-	-	-	V
Reverse recovery time $I_F = 200\text{ A}$ , $V_R = -600\text{ V}$ , $V_{GE} = 0\text{ V}$ $di_F/dt = -2000\text{ A}/\mu\text{s}$ , $T_j = 125\text{ °C}$	$t_{rr}$	-	-	-	$\mu\text{s}$
Reverse recovery charge $I_F = 200\text{ A}$ , $V_R = -600\text{ V}$ , $V_{GE} = 0\text{ V}$ $di_F/dt = -2000\text{ A}/\mu\text{s}$ $T_j = 25\text{ °C}$ $T_j = 125\text{ °C}$	$Q_{rr}$	-	-	-	$\mu\text{C}$

**Electrical Characteristics**, at  $T_j = 25\text{ °C}$ , unless otherwise specified

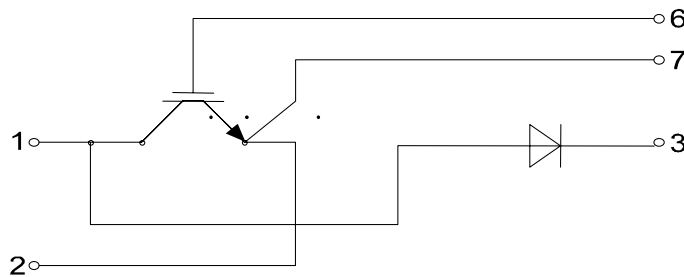
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>Chopper Diode</b>					
Chopper diode forward voltage $I_{FC} = 300\text{ A}$ , $V_{GE} = 0\text{ V}$ , $T_j = 25\text{ °C}$ $I_{FC} = 300\text{ A}$ , $V_{GE} = 0\text{ V}$ , $T_j = 125\text{ °C}$	$V_{FC}$	- -	2 1.8	2.5 -	V
Reverse recovery time, chopper $I_{FC} = 300\text{ A}$ , $V_R = -600\text{ V}$ , $V_{GE} = 0\text{ V}$ $di_F/dt = -2500\text{ A}/\mu\text{s}$ , $T_j = 25\text{ °C}$	$t_{rrC}$	-	500	-	ns
Reverse recovery charge, chopper $I_{FC} = 300\text{ A}$ , $V_R = -600\text{ V}$ , $V_{GE} = 0\text{ V}$ $di_F/dt = -2500\text{ A}/\mu\text{s}$ $T_j = 25\text{ °C}$ $T_j = 125\text{ °C}$	$Q_{rrC}$	- -	14 40	- -	$\mu\text{C}$



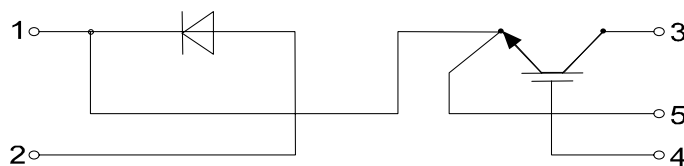
**Gehäusemaße / Schaltbild**  
**Package outline / Circuit diagram**



GAL type



GAR type



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